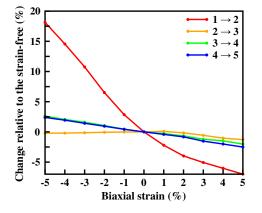
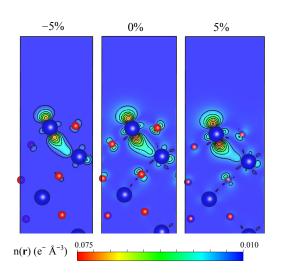
ESI: Modulation of band alignment with water redox potentials by biaxial strain on orthorhombic  $NaTaO_3$  thin film

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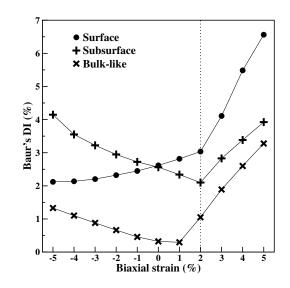


S.1 The change on the interlayer distance with the biaxial strain emphasizing the sensitivity of the two outermost layers to strain. In legend, the distance  $1 \rightarrow 2$  measures the distance between the surface and subsurface layers,  $2 \rightarrow 3$  the one between the subsurface and the first bulk-like layer. Distances  $3 \rightarrow 4, 4 \rightarrow 5$  are measured between the layers inside the bulk-like region.



S.2 The charge density  $n(\mathbf{r})$  of the surface states evaluated at each strain state. The level curves clearly show the  $5d_{3z^2-r^2} - 5d_{yz}$  overlap between surface and subsurface Ta 5d and their increase with tension.

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S.3 The change in the Baur's distortion index with biaxial strain emphasizing the inflection point at 2%. Further increases in tension lead to a more severe distortion of the overall thin film structure.

The compressive strain increases the energetic gaps, while the tensile strain initially decreases them. For biaxial strain values higher than 2%, both the bandgap and the defect gap increase with the tension. The change in the reduction trend at the 2% mark comes from the distortions of the TaO<sub>6</sub> octahedra (bulk-like and subsurface) and TaO<sub>4</sub> surface tetrahedra evaluated with the Baur's distortion index<sup>1</sup>:

$$DI = \frac{1}{N} \sum_{i=1}^{N} \frac{|l_i - \langle l \rangle|}{\langle l \rangle}$$

where  $l_i$  is the Ta-O bond distance,  $\langle l \rangle$  the average bond distance, and N = 4 (6) for the surface (subsurface) polyhedra. Although the electrostatic repulsion on Ta 5*d* orbitals keeps decreasing with the tensile increase, the distortion of Ta polyhedra changes the steric interactions related to non-bonding 5*d* orbitals. Again from the crystal field picture, the energy levels of Ta 5*d* orbitals are minimal in the octahedral symmetry because there are no interactions between O 2*p* with Ta non-bonding 5*d*<sub>xy</sub>, 5*d*<sub>yz</sub> and 5*d*<sub>xz</sub> orbitals. As the ligands depart from the pristine octahedral configuration, the repulsive O2*p*-Ta5*d* interactions increase, increasing the energy levels of the involved 5*d* states. The overall effect is the compensation of the Ta-O distance elongation on the energy levels.

## Notes and references

1 W. H. Baur, Acta Crystallographica Section B Structural Crystallography and Crystal Chemistry, 1974, **30**, 1195–1215.

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